

MPS6515/MMBT6515

NPN General Purpose Amplifier

- This device is designed as a general purpose amplifier and switch.
- The useful dynamic range extends to 100mA as a switch and to 100MHz as an amplifier.





1. Emitter 2. Base 3. Collector 1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings* T_C=25°C unless otherwise noted

Symbol	Parameter		Value	Units
V _{CEO}	Collector-Emitter Voltage		25	V
V _{CBO}	Collector-Base Voltage		40	V
V _{EBO}	Emitter-Base Voltage		4.0	V
I _C	Collector current	- Continuous	200	mA
T _J , T _{stg}	Junction and Storage Temperature		-55 ~ +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- NOTES:

 1) These ratings are based on a maximum junction temperature of 150 degrees C.

 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characte	eristics				•
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_C = 0.5 \text{mA}, I_B = 0$	25		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 10\mu A, I_{E} = 0$	40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_C = 10\mu A, I_C = 0$	4.0		V
I _{CBO}	Collector Cutoff Current	$V_{CE} = 30V, I_{E} = 0$		50	nA
I _{CBO}	Collector Cutoff Current	$V_{CB} = 30V, I_{E} = 0, T = 60^{\circ}C$		1.0	μΑ
On Characte	eristics *	•			
h _{FE}	DC Current Gain	$I_C = 2.0 \text{mA}, V_{CE} = 10 \text{V}$ $I_C = 100 \text{mA}, V_{CE} = 10 \text{V}$	250 150	500	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$		0.5	V
	I Characteristics	·	•	•	
C _{obo}	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 100kHz$		3.5	pF
Pulse Test: Pulse	e Width ≤ 300μs, Duty Cycle ≤ 2.0%	•			•

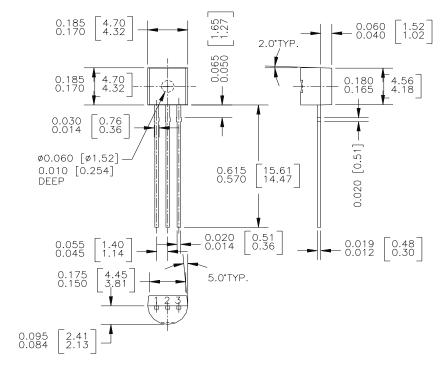
Thermal Characteristics T_A=25°C unless otherwise noted

Cumbal	Devemeter	Max.		Units	
Symbol	Parameter	MPS6515	*MMBT6515	Units	
P _D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W	

^{*} Device mounted on FR-4 PCB 1.6" × 0.06"

Package Dimensions

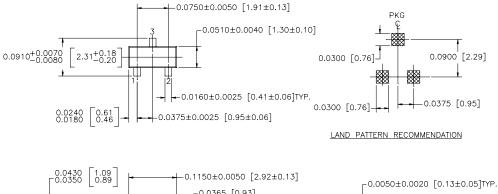
TO-92

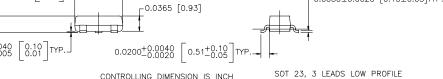


Dimensions in Millimeters

Package Dimensions (Continued)

SOT-23





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	FACT™	ImpliedDisconnect™	PACMAN™	SPM™
ActiveArray™	FACT Quiet series™	ISOPLANAR™	POP™	Stealth™
Bottomless™	FAST [®]	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
$CROSSVOLT^{TM}$	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic [®]
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C TM	OCXTM	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franchise™		OPTOLOGIC [®]	SILENT SWITCHER®	VCX™
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Fairchild Semiconductor: MMBT6515 MMBT6515_Q